

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT8002-3 (MLPAK33) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- Fully automotive qualified to AEC-Q101 at 175°C
- Side-wettable flanks for optical solder inspection

### 3. Applications

- LED Lighting
- Switching circuits
- DC-DC conversion

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	60	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C	[1]	-	-	21	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	-	27	W
Static chara	acteristics	·	·	·			
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 25 °C		-	23.7	29	mΩ
Dynamic ch	naracteristics				_		
Q <sub>GD</sub>	gate-drain charge	$V_{DS}$ = 30 V; I <sub>D</sub> = 5.6 A; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C		-	2.4	-	nC

[1] 21 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

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# 5. Pinning information

Table 2. P	inning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source		
3	S	source		D
4	G	gate		
5	D	drain		G-UFFA
6	D	drain		mbb076 S
7	D	drain	8765	
8	D	drain	MLPAK33 (SOT8002-3)	

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BXK9Q29-60E	MLPAK33	plastic thermal enhanced surface mounted package with side-wettable flanks (SWF); mini leads; 8 terminals;pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-3			

### 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BXK9Q29-60E	7aa

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

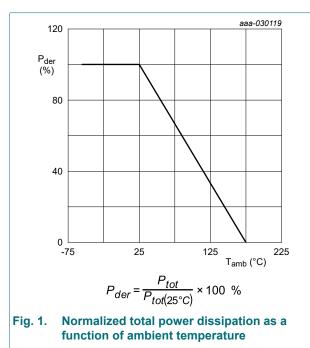
Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	60	V
V <sub>GS</sub>	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C	[1]	-	21	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C		-	14.5	А
I <sub>DM</sub>	peak drain current	single pulse; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C		-	84	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	27	W
Tj	junction temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-55	175	°C
Source-drain	n diode			_		
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	21	А
I <sub>SM</sub>	peak source current	single pulse; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}C$	[1]	-	84	Α
Avalanche r	uggedness			-		
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$V_{sup}$ < 60 V; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; R <sub>GS</sub> = 50 Ω; I <sub>D</sub> = 15.8 A; unclamped	[2] [3]	-	25	mJ
I <sub>AS</sub>	non-repetitive avalanche current	T <sub>j(init)</sub> = 25 °C	[4]	-	15.8	A
		1	1		1	

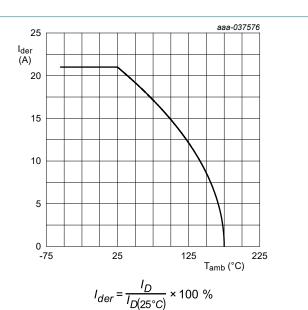
 21 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

[4] Protected by 100% test.

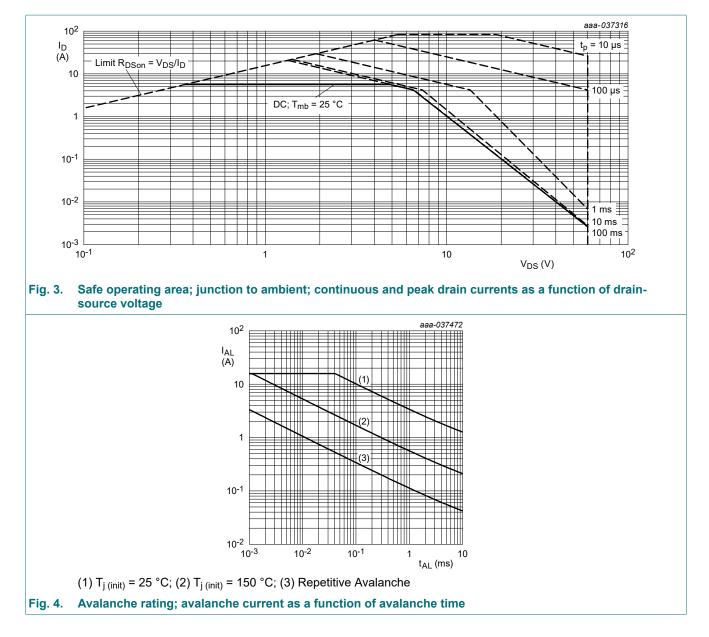




21 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of ambient temperature

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## 9. Thermal characteristics

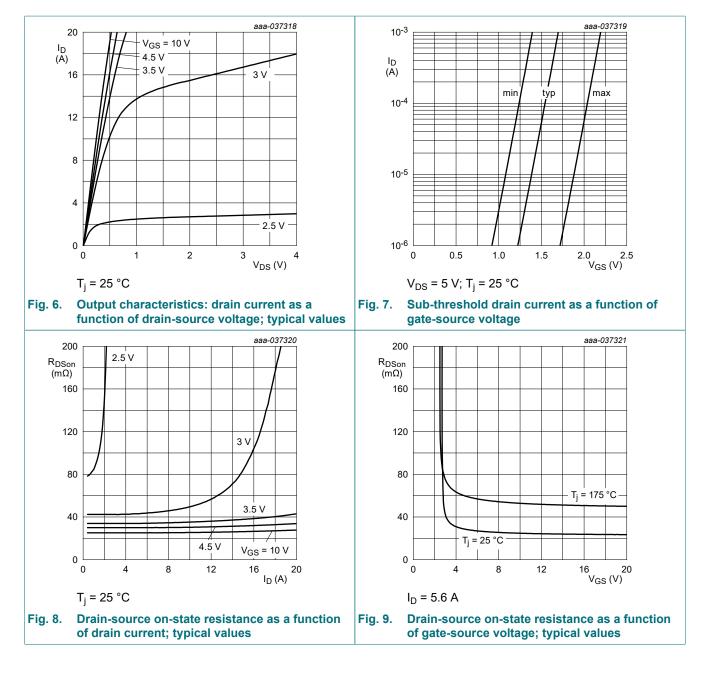
Symbol	Parameter	Conditions		M	in Typ	Max	Unit
₹th(j-mb)	thermal resistance from junction to mounting base			-	3.5	5.5	K/W
10 Z <sub>th(j-mb)</sub> (K/W) 0.50= 1 <u>0.25</u> =	bycle = 1 0.75 0.33 0.20					aa-037317	
10-1	0.05					$\delta = \frac{t_p}{T}$	
10 <sup>-2</sup> 10 <sup>-5</sup>	10 <sup>-4</sup>	10 <sup>-3</sup>	10 <sup>-2</sup>	10-	1 t <sub>p</sub> (s)	1	

### **10. Characteristics**

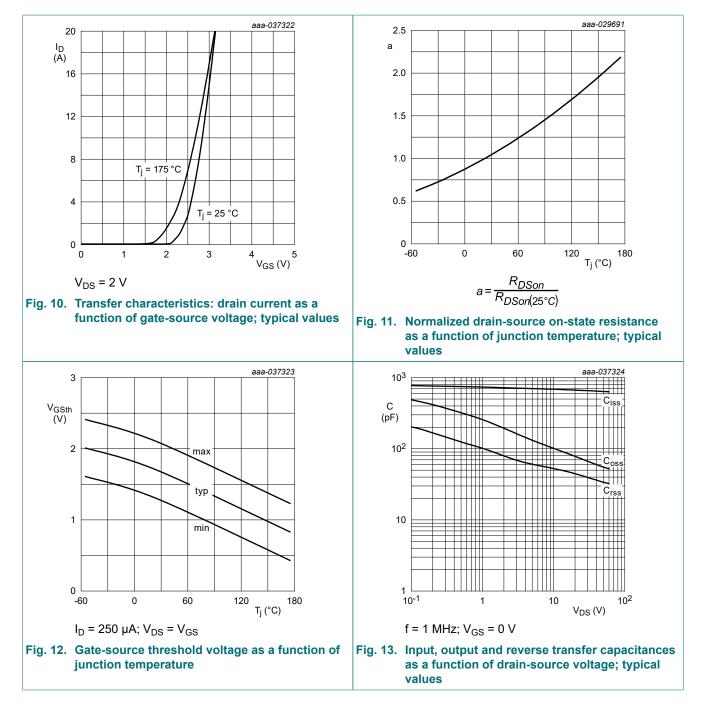
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	60	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	1.3	1.7	2.1	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μA
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	-	20	μA
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	-	400	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	0.1	μA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-0.1	μA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 25 °C	-	23.7	29	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 105 °C	-	39	51.4	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 125 °C	-	42.4	55.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 175 °C	-	52	64	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 25 °C	-	28	38	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 105 °C	-	45.3	63.9	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 125 °C	-	49.2	69.5	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 175 °C	-	60.9	83.6	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 5 V; I <sub>D</sub> = 5.6 A	-	18.6	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	2	-	Ω
Dynamic ch	naracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = 30 V; I <sub>D</sub> = 5.6 A; V <sub>GS</sub> = 10 V;	-	12	18	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.6	-	nC
Q <sub>GD</sub>	gate-drain charge	-	-	2.4	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 30 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	660	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	67	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	40	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 30 V; I <sub>D</sub> = 5.6 A; V <sub>GS</sub> = 10 V;	-	3	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 5 Ω; T <sub>j</sub> = 25 °C	-	4	-	ns
t <sub>d(off)</sub>	turn-off delay time	-	-	13	-	ns
<sup>t</sup> f	fall time		-	5	-	ns
Source-drai	in diode	· · · · ·	I			
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 2.5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.8	1	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 2.5 A; dI <sub>S</sub> /dt = -100 A/μs;	-	13	-	ns
Q <sub>r</sub>	recovered charge	V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C		7	_	nC

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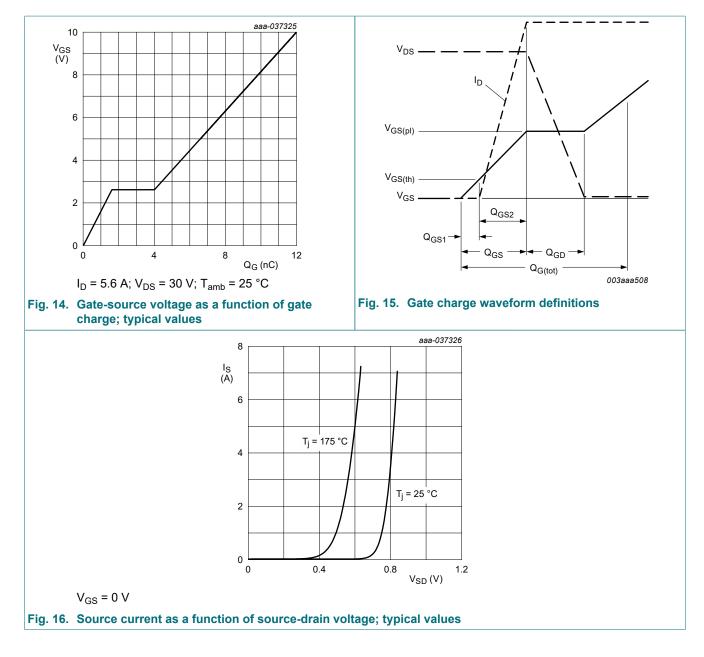
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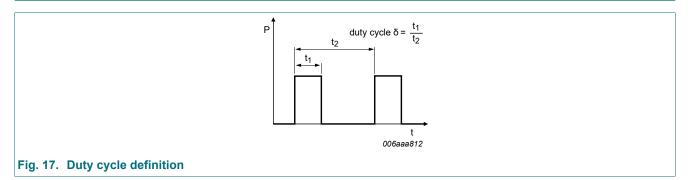
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### **11. Test information**

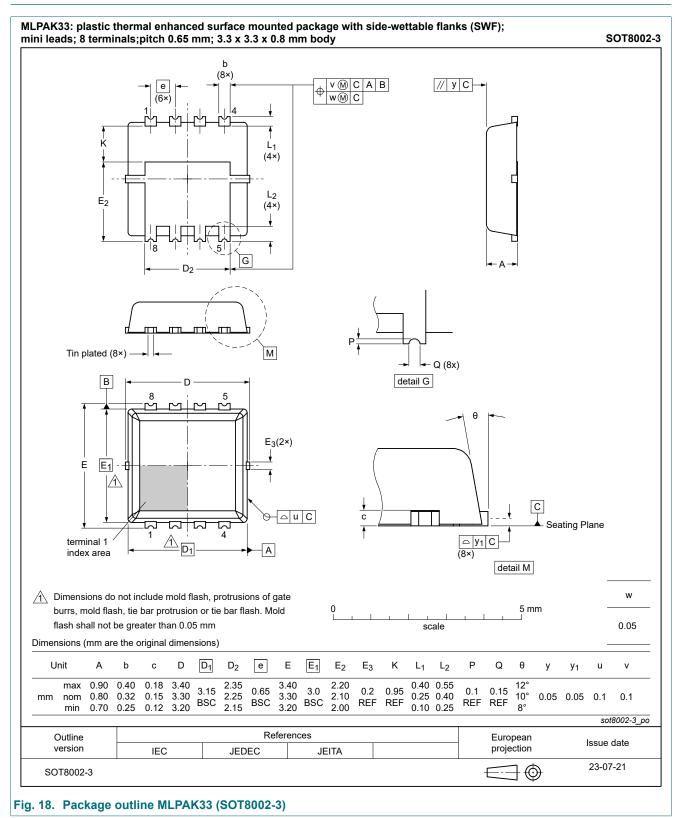


#### **Quality information**

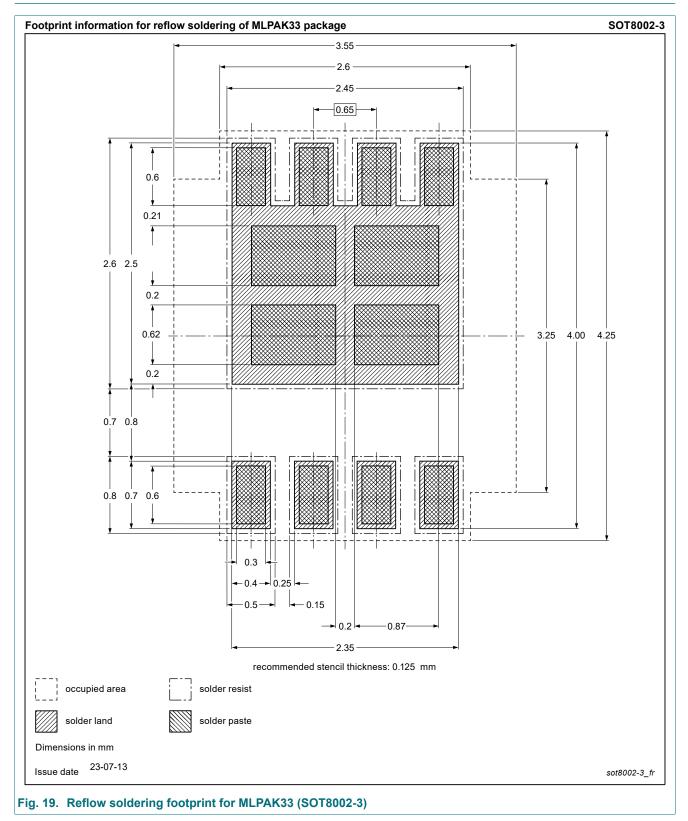
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

BXK9Q29-60E

# 12. Package outline



### 13. Soldering



# 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BXK9Q29-60E v.1	20240519	Product data sheet	-	-		

BXK9Q29-60E

### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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